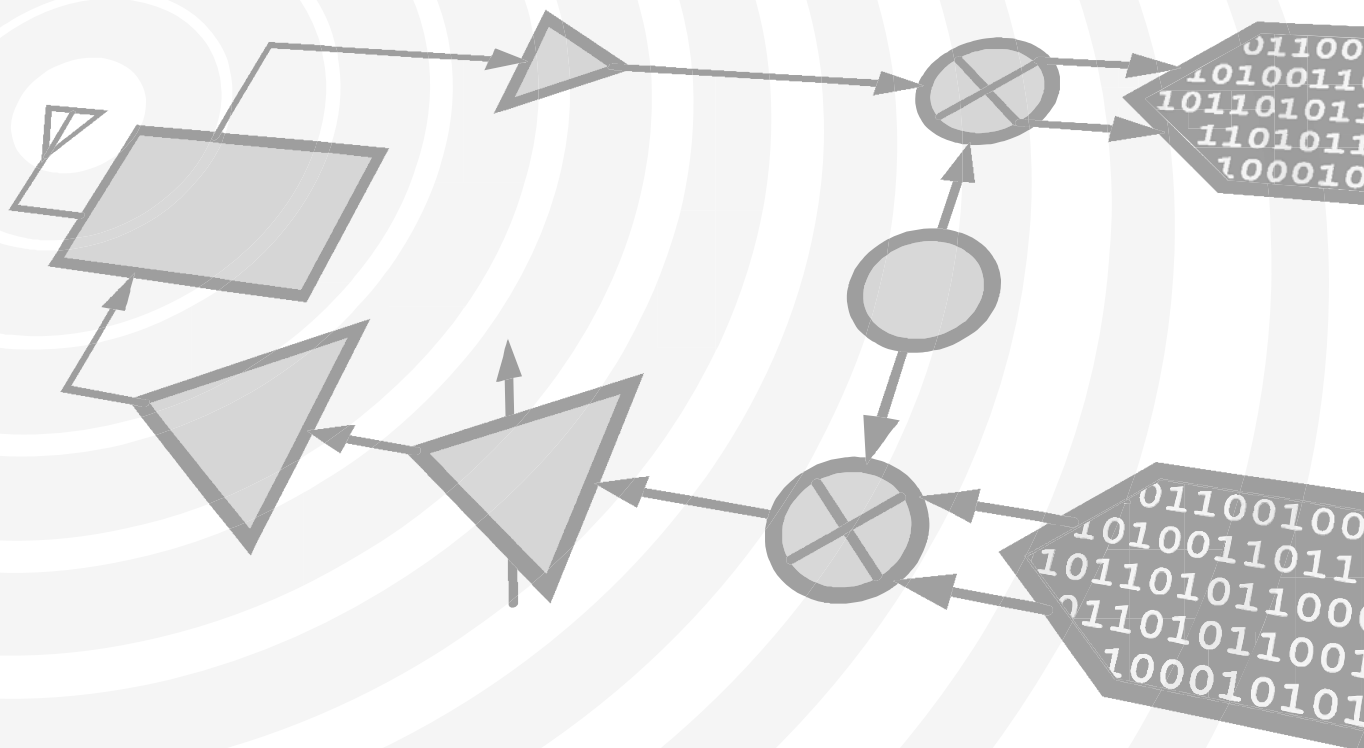




NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



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Typical Applications

The HMC219AMS8 / HMC219AMS8E is ideal for:

- UNII & HiperLAN
- ISM
- Microwave Radios

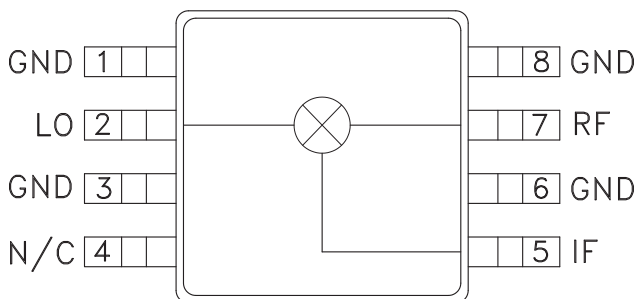
Features

Ultra Small Package: MSOP8

Conversion Loss: 8.5 dB

LO / RF Isolation: 25 dB

Functional Diagram



General Description

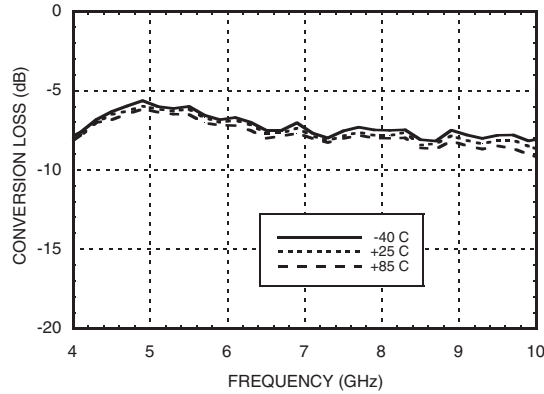
The HMC219AMS8 & HMC219AMS8E are ultra miniature double-balanced mixers in 8 lead plastic surface mount packages (MSOP). This passive MMIC mixer is constructed of GaAs Schottky diodes and novel planar transformer baluns on the chip. The device can be used as an upconverter, downconverter, bi-phase (de)modulator, or phase comparator. The consistent MMIC performance will improve system operation and assure regulatory compliance.

Electrical Specifications, $T_A = +25^\circ \text{C}$, As a Function of LO Drive

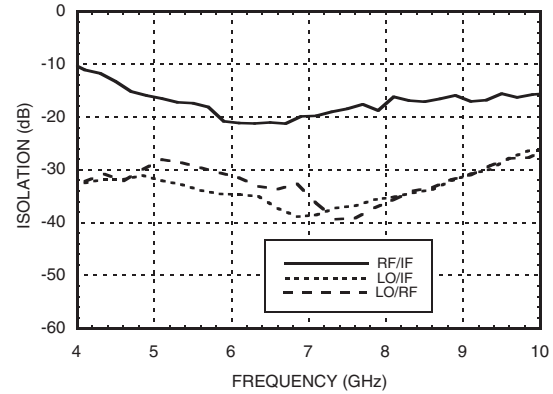
Parameter	LO = +13 dBm IF = 100 MHz			LO = +11 dBm IF = 100 MHz			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range, RF & LO	4.5 - 9.0			4.5 - 8.6			GHz
Frequency Range, IF	DC - 2.5			DC - 2.5			GHz
Conversion Loss		8.5	10		8.5	10	dB
Noise Figure (SSB)		8.5	10		8.5	10	dB
LO to RF Isolation	17	25		20	25		dB
LO to IF Isolation	17	25		20	25		dB
IP3 (Input)	15	21		15	21		dBm
1 dB Gain Compression (Input)	7	10		5	8		dBm

GaAs MMIC SMT DOUBLE-BALANCED MIXER, 4.5 - 9 GHz

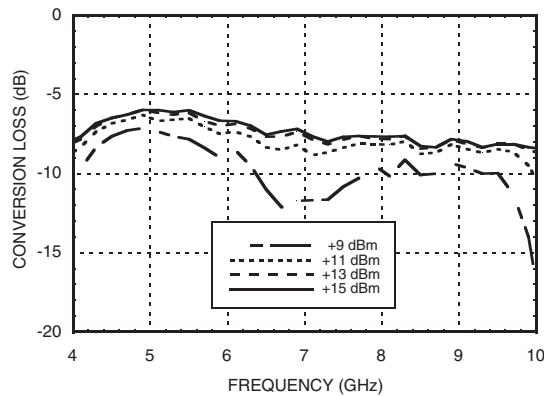
Conversion Loss vs Temperature @ LO = +13 dBm



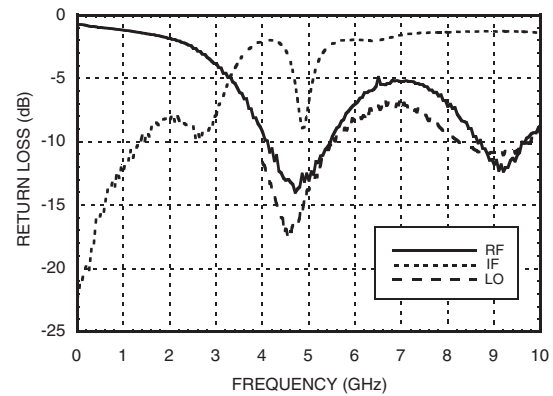
Isolation @ LO = +13 dBm



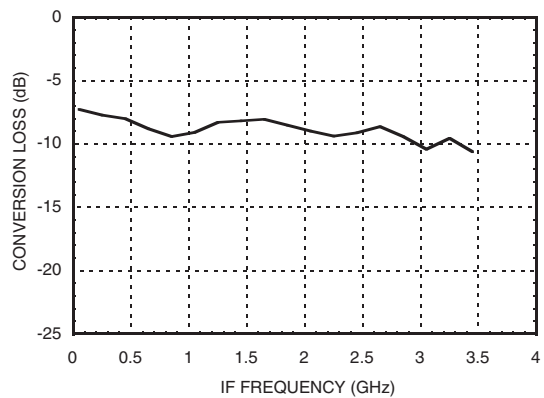
Conversion Loss vs. LO Drive



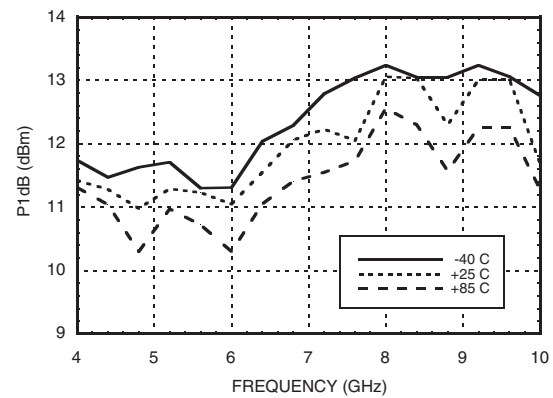
Return Loss @ LO = +13 dBm



IF Bandwidth @ LO = +13 dBm

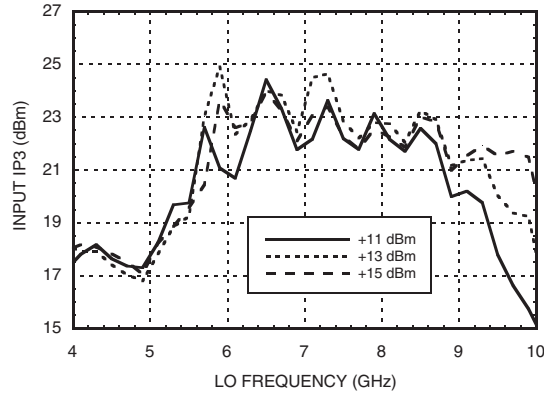


P1dB vs. Temperature LO = +13 dBm

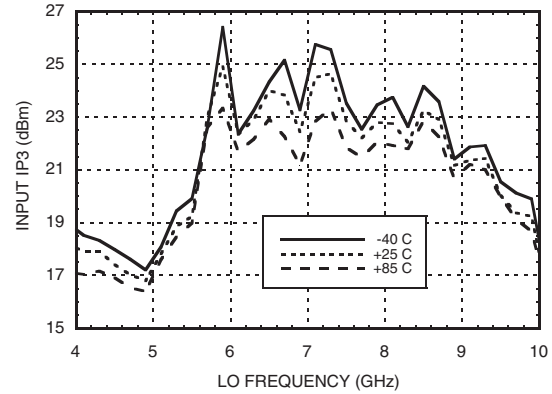


GaAs MMIC SMT DOUBLE-BALANCED MIXER, 4.5 - 9 GHz

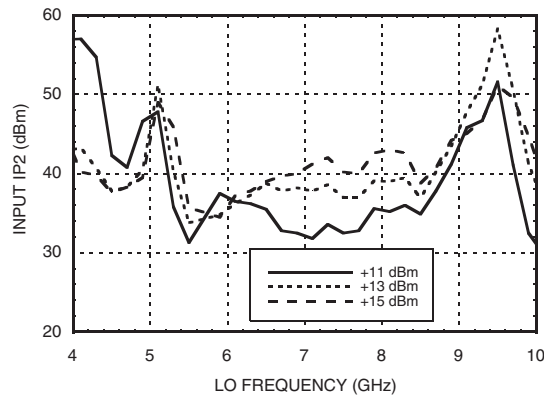
Input IP3 vs. LO Drive



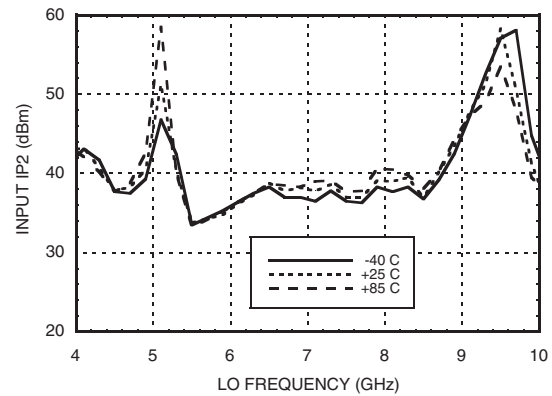
Input IP3 vs. Temperature @ LO = +13 dBm



Input IP2 vs. Drive



Input IP2 vs. Temperature @ LO = +13 dBm





MICROWAVE CORPORATION v00.0810



HMC219AMS8 / 219AMS8E

GaAs MMIC SMT DOUBLE-BALANCED MIXER, 4.5 - 9 GHz

MxN Spurious Outputs

mRF	nLO				
	0	1	2	3	4
0	xx	9	12	16	34
1	19	0	22	32	49
2	62	63	59	62	66
3	80	69	82	69	79
4	79	81	81	80	83

RF = 6 GHz @ -10 dBm
LO = 6.1 GHz @ +13 dBm
All values in dBc below the IF power level (-1RF + 1LO).

Harmonics of LO

LO Freq. (GHz)	nLO Spur at RF Port			
	1	2	3	4
4.0	31	22	32	58
5.0	32	21	30	47
6.0	40	28	28	49
7.0	32	35	53	48
8.0	27	40	57	55
9.0	22	52	48	xx

LO = +13 dBm
Values in dBc below input LO level measured at the RF port.

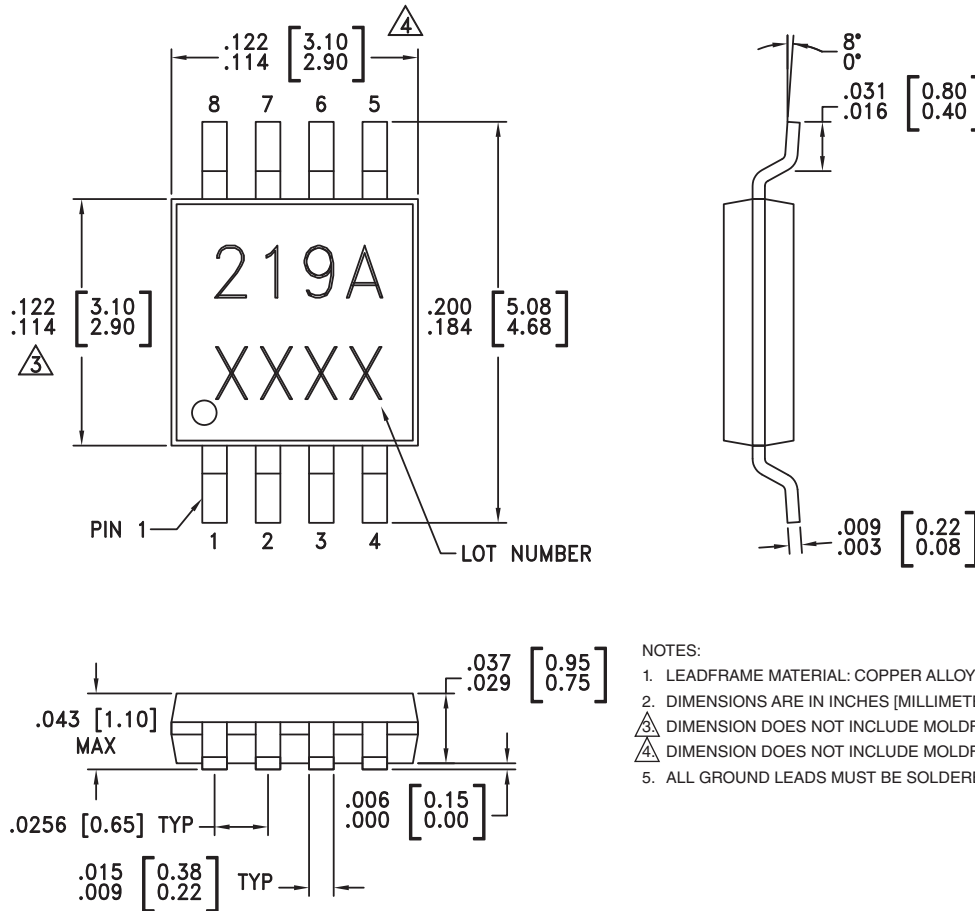
Absolute Maximum Ratings

RF / IF Input	+13 dBm
LO Drive	+27 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



Package Information

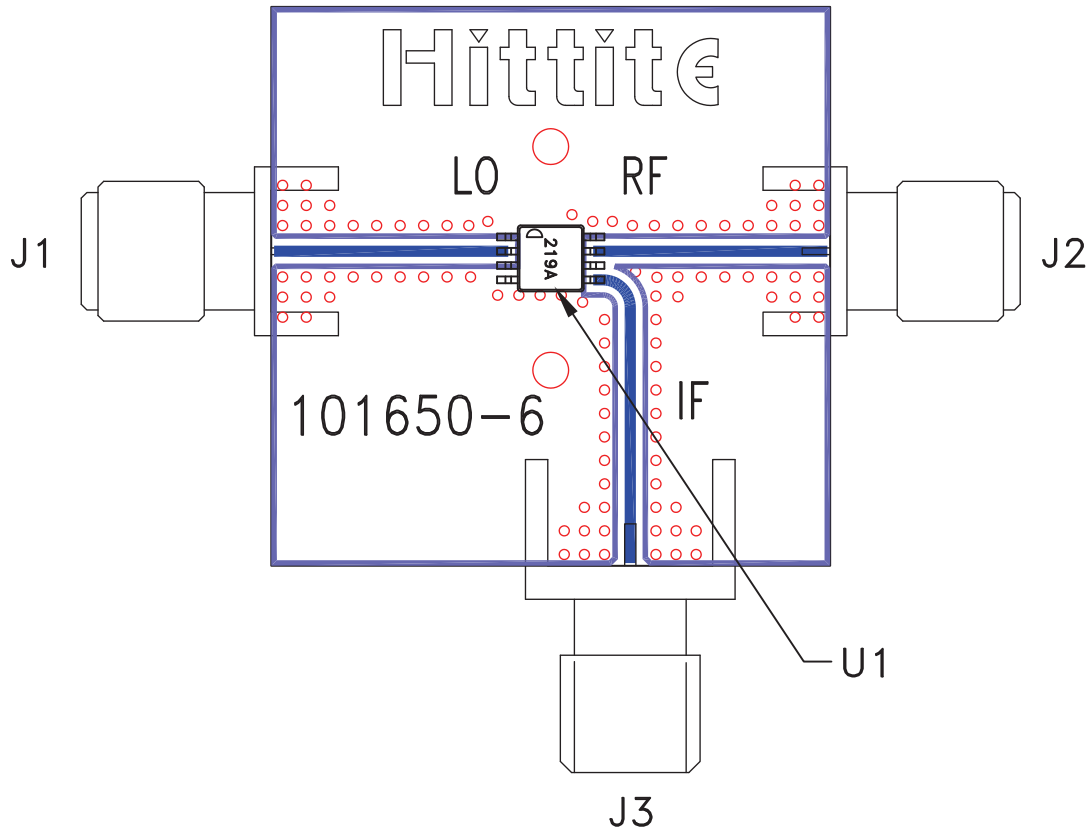
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC219AMS8	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	219A XXXX
HMC219AMS8E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	219A XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

Evaluation Circuit Board



List of Materials for Evaluation PCB 103350 ^[1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
U1	HMC219AMS8 / HMC219AMS8E Mixer
PCB [2]	101650 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.